L Number	Hits	Search Text	DB	Time stamp
1	3624	(light adj emitting or led or oled or pixel)	USPAT;	2003/11/20 10:07
		and (TFT or thin adj film adj transistor)	US-PGPUB;	
		near10 (capacitor or capacitive)	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
2	1413	(light adj emitting or led or oled or pixel)	USPAT;	2003/11/20 10:08
		and (TFT or thin adj film adj transistor)	US-PGPUB;	
		near10 (capacitor or capacitive) near10	EPO; JPO;	
i		(source or drain)	DERWENT;	
_	100	/14-ht - 24	IBM_TDB	0000/11/00 10 11
3	190	(light adj emitting or led or oled or pixel)	USPAT;	2003/11/20 13:14
		same (TFT or thin adj film adj transistor)	US-PGPUB;	
		same (capacitor or capacitive) near5 (over	EPO; JPO;	
	13.	or on or above or top or higher or upon)	DERWENT;	
		near4 (TFT or transistor or gate or insulating or insulative or interlayer or	IBM_TDB	
	,	dielectric)		
5	12	(light adj emitting or led or oled or pixel)	USPAT;	2003/11/20 13:15
_	13	same (TFT or thin adj film adj transistor)	US-PGPUB;	2003/11/20 13:15
		same (capacitor or capacitive) near5 (over	EPO; JPO;	
		or on or above or top or higher or upon)	DERWENT;	
		near4 (TFT or transistor or gate or	IBM TDB	
		insulating or insulative or interlayer or		
		dielectric) and (oled or organic adj light		
		adj emitting)		
6	13	(light adj emitting or led or oled or pixel)	USPAT;	2003/11/20 13:36
		same (TFT or thin adj film adj transistor)	US-PGPUB;	]
		same (capacitor or capacitive) near5 (over	EPO; JPO;	
		or on or above or top or higher or upon)	DERWENT;	
		near4 (TFT or transistor or gate or	IBM_TDB	
		insulating or insulative or interlayer or		. 4
		dielectric) and (oled or organic adj light		
7	270	adj emitting or o-led or organic adj led)	******	0000/00/00 00
7	279	, , , , , , , , , , , , , , , , , , , ,	USPAT;	2003/11/20 14:22
		(capacitor or capacitive) near3 (holding or	US-PGPUB;	
		storage or storing or retaining or retainer or retained) and (oled or organic adj light	EPO; JPO;	
		adj emitting or o-led or organic adj led)	DERWENT; IBM TDB	
8	183	(TFT or thin adj film adj transistor) and	USPAT;	2003/11/20 14:30
-	103	(capacitor or capacitive) near3 (holding or	US-PGPUB;	2003/11/20 14:30
		storage or storing or retaining or retainer	EPO; JPO;	
		or retained) and (oled or organic adj light	DERWENT;	
		adj emitting or o-led or organic adj led)	IBM TDB	
ļ		and (driving) near4 (tft or transistor) and		
		switching near3 (tft or transistor)		
9	28	(TFT or thin adj film adj transistor) and	USPAT;	2003/11/20 14:32
		(second or secondary or plural or plurality	US-PGPUB;	
		or multiple or multiplicity) near2	EPO; JPO;	
		(capacitor or capacitive) near3 (holding or	DERWENT;	
j		storage or storing or retaining or retainer	IBM_TDB	
		or retained) and (oled or organic adj light		
	_	adj emitting or o-led or organic adj led)		
10	3	(US-6118506-\$ or US-6423973-\$ or	USPAT	2003/11/20 14:35
i		US-6490014-\$).did.	I	1